

Switching (60V, 300mA)

RK7002A

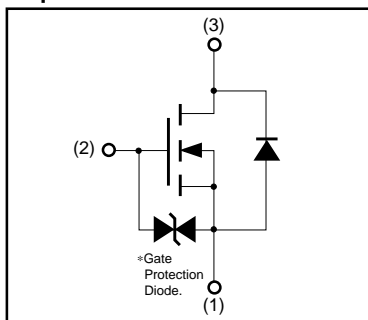
●Features

- 1) Low on-resistance.
- 2) High ESD
- 3) High-speed switching.
- 4) Low-voltage drive (4V).
- 5) Easily designed drive circuits.
- 6) Easy to use in parallel.

●Structure

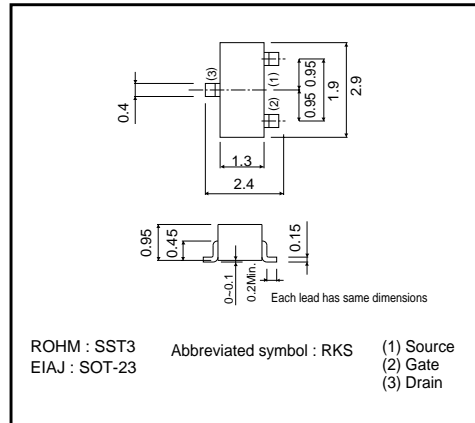
Silicon N-channel
MOSFET transistor

●Equivalent circuit



* A protection diode has been built in between the gate and the source to protect against static electricity when the product is in use.
Use the protection circuit when fixed voltages are exceeded.

●External dimensions (Units : mm)



●Absolute maximum ratings (Ta=25°C)

| Parameter | Symbol | Limits | Unit |
|-------------------------|------------|----------------|--------|
| Drain-source voltage | V_{DSS} | 60 | V |
| Gate-source voltage | V_{GSS} | ± 20 | V |
| Drain current | Continuous | I_D | 300 mA |
| | Pulsed | I_{DP}^{*1} | 1.2 A |
| Drain reverse current | Continuous | I_{DR} | 300 mA |
| | Pulsed | I_{DRP}^{*1} | 1.2 A |
| Total power dissipation | P_D^{*2} | 200 | mW |
| Channel temperature | T_{ch} | 150 | °C |
| Storage temperature | T_{stg} | -55~+150 | °C |

*1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

*2 When using 1x0.75x0.062 inch glass epoxy board.

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●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Test Conditions |
|----------------------------------|------------------------|------|------|------|------|---|
| Gate leakage current | I _{GSS} | - | - | ±10 | μA | V _{GS} =±20V, V _{DS} =0V |
| Drain-source breakdown voltage | V _{(BR)DSS} | 60 | - | - | V | I _D =10μA, V _{GS} =0V |
| Drain cutoff current | I _{DSS} | - | - | 1 | μA | V _{DS} =60V, V _{GS} =0V |
| Gate threshold voltage | V _{GS(th)} | 1 | - | 2.5 | V | V _{DS} =10V, I _D =1mA |
| Drain-source on-state resistance | R _{DS(on)} *1 | - | 0.7 | 1.0 | Ω | I _D =300mA, V _{GS} =10V |
| | | - | 1.1 | 1.5 | | I _D =300mA, V _{GS} =4V |
| Forward transfer admittance | Y _{fs} *1 | 200 | - | - | mS | V _{DS} =10V, I _D =300mA |
| Input capacitance | C _{iss} | - | 33 | - | pF | V _{DS} =10V |
| Output capacitance | C _{oss} | - | 14 | - | pF | V _{GS} =0V |
| Reverse transfer capacitance | C _{rss} | - | 9 | - | pF | f=1MHz |
| Turn-on delay time | t _{d(on)} *2 | - | 6 | - | ns | I _D =150mA, V _{DD} =30V |
| Rise time | t _r *2 | - | 5 | - | ns | V _{GS} =10V |
| Turn-off delay time | t _{d(off)} *2 | - | 13 | - | ns | R _L =200Ω |
| Fall time | t _f *2 | - | 80 | - | ns | R _{GS} =10Ω |
| Total gate charge | Q _g *2 | - | 3 | 6 | nC | V _{DD} =30V |
| Gate-source charge | Q _{gs} *2 | - | 0.6 | - | nC | V _{GS} =10V |
| Gate-drain charge | Q _{gd} *2 | - | 0.5 | - | nC | I _D =200mA |

*1 P_W≤300μs, Duty cycle≤1%
 *2 Pulsed

●Packaging specifications

| | | |
|---------|------------------------------|--------|
| | Package | Taping |
| | Code | T116 |
| Type | Basic ordering unit (pieces) | 3000 |
| RK7002A | | ○ |

●Electrical characteristic curves

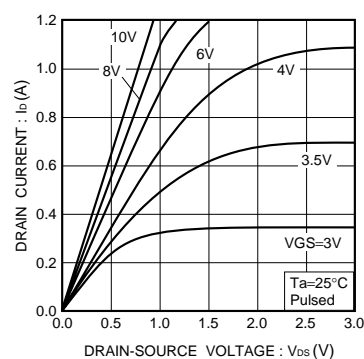


Fig.1 Typical output characteristics

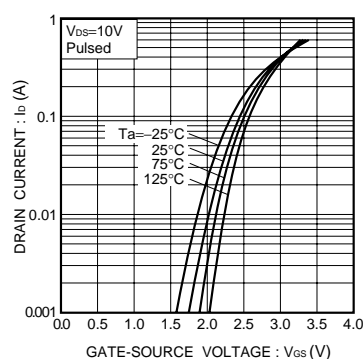


Fig.2 Typical transfer characteristics

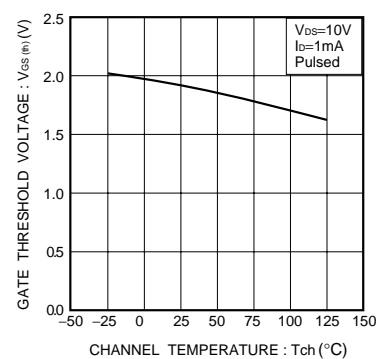


Fig.3 Gate threshold voltage vs. channel temperature

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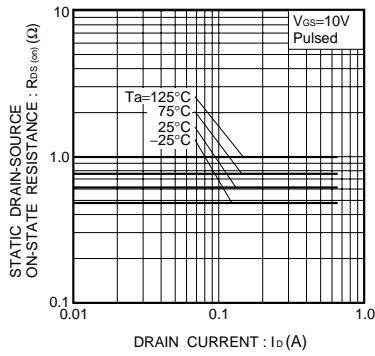


Fig.4 Static drain-source on-state resistance vs. drain current (I)

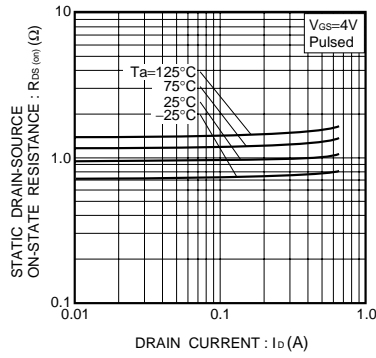


Fig.5 Static drain-source on-state resistance vs. drain current (II)

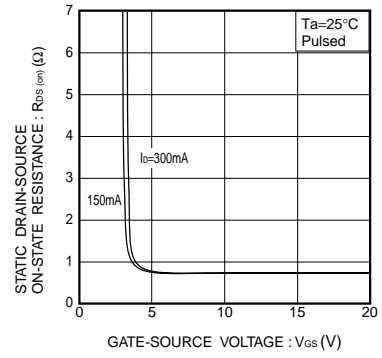


Fig.6 Static drain-source on-state resistance vs. gate-source voltage

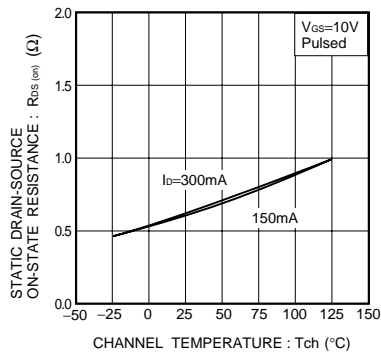


Fig.7 Static drain-source on-state resistance vs. channel temperature

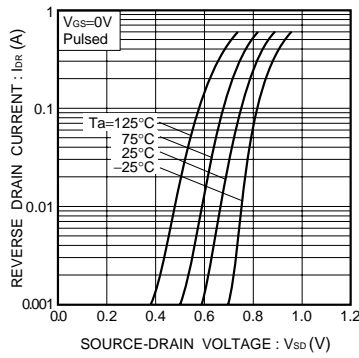


Fig.8 Reverse drain current vs. source-drain voltage (I)

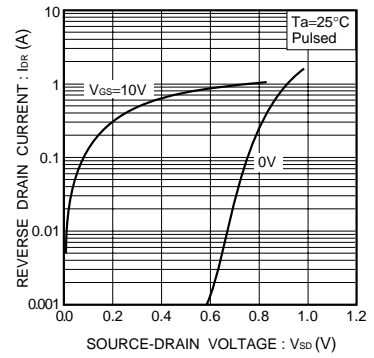


Fig.9 Reverse drain current vs. source-drain voltage (II)

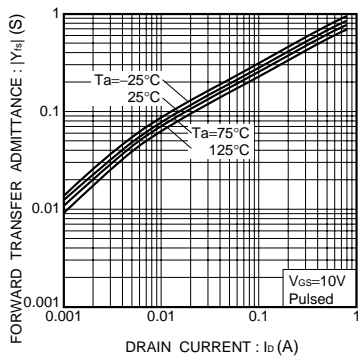


Fig.10 Forward transfer admittance vs. drain current

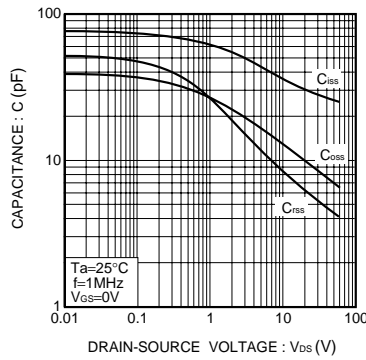


Fig.11 Typical capacitance vs. drain-source voltage

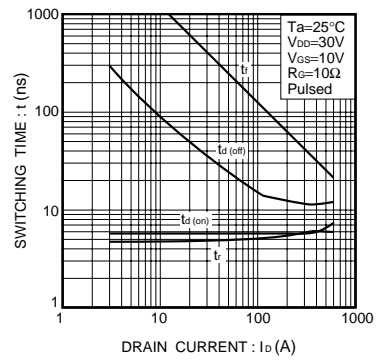


Fig.12 Switching characteristics (See Figures 13 and 14 for the measurement circuit and resultant waveforms)

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● Switching characteristics measurement circuit

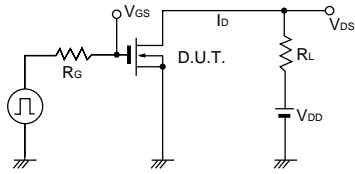


Fig.13 Switching time measurement circuit

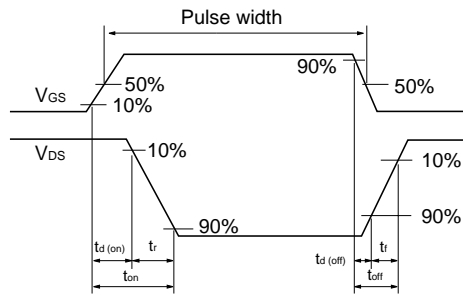


Fig.14 Switching time waveforms

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